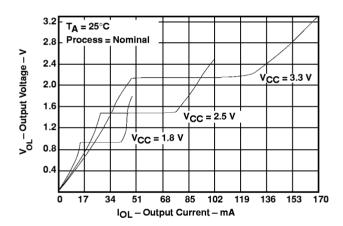
## SN74AVC125 QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS

SCES253 - APRIL 1999

- ► EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process
- DOC™ (Dynamic Output Control) Circuit Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- Dynamic Drive Capability Is Equivalent to Standard Outputs With I<sub>OH</sub> and I<sub>OL</sub> of ±24 mA at 2.5-V V<sub>CC</sub>
- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Package Options Include Plastic Small-Outline (D), Thin Very Small-Outline (DGV), and Thin Shrink Small-Outline (PW) Packages

## description

A Dynamic Output Control (DOC) circuit is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical V<sub>OL</sub> vs I<sub>OL</sub> and V<sub>OH</sub> vs I<sub>OH</sub> curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC*<sup>TM</sup>) *Circuitry Technology and Applications*, literature number SCEA009.



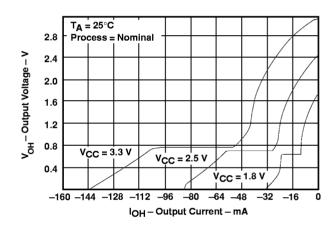


Figure 1. Output Voltage vs Output Current

This quadruple bus buffer gate is operational at 1.2-V to 3.6-V  $V_{CC}$ , but is designed specifically for 1.65-V to 3.6-V  $V_{CC}$  operation.

The SN74AVC125 features independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable  $(\overline{OE})$  input is high.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SN74AVC125 is characterized for operation from -40°C to 85°C.



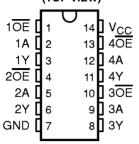
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## assigninents

D, DGV, OR PW PACKAGE (TOP VIEW)

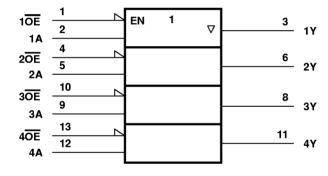


# FUNCTION TABLE (each buffer)

INP	JTS	OUTPUT
ŌĒ	Α	Y
L	Н	Τ
L	L	L
Н	Χ	Z

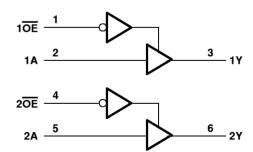
# logic symbol†

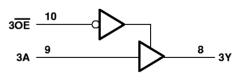
PRODUCT PREVIEW

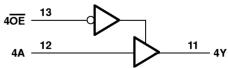


 $<sup>\</sup>ensuremath{^{\dagger}}$  This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## logic diagram (positive logic)







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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

This device is fully specified for partial-power-down applications using l<sub>off</sub>. The l<sub>off</sub> circuitry disables the output, preventing damaging current backflow through the device when it is powered down.

Supply voltage range, V <sub>CC</sub> Input voltage range, V <sub>I</sub> (see Note 1)  Voltage range applied to any output in the high impedance or newer off state. V-	
Voltage range applied to any output in the high-impedance or power-off state, V <sub>O</sub> (see Note 1)	
Voltage range applied to any output in the high or low state, V <sub>O</sub>	
(see Notes 1 and 2)	$\dots$ -0.5 V to V <sub>CC</sub> + 0.5 V
Input clamp current, $I_{ K }(V_1 < 0)$	
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	
Continuous output current, IO	
Continuous current through each V <sub>CC</sub> or GND	
Package thermal impedance, θ <sub>JA</sub> (see Note 3): D package	
DGV package	
PW package	
Storage temperature range, T <sub>stq</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.
- 3. The package thermal impedance is calculated in accordance with JESD 51.



## SN74AVC125 QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS

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## recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
VCC	Cumply valtage	Operating	1.65	3.6	V
	Supply voltage	Data retention only	1.2		v
.,		V <sub>CC</sub> = 1.2 V			
	High level innut valtage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.65 × V <sub>CC</sub>		v
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		, v
		V <sub>CC</sub> = 3 V to 3.6 V	2	2	
		V <sub>CC</sub> = 1.2 V		GND	
V.	Lavy lavyal innovativa labora	V <sub>CC</sub> = 1.65 V to 1.95 V		0.35 × V <sub>CC</sub>	V
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	0.7		
		V <sub>CC</sub> = 3 V to 3.6 V		0.8	
٧ <sub>I</sub>	Input voltage	•	0	3.6	٧
V <sub>O</sub>	Outrot velta e -	Active state	Active state 0	Vcc	V
	Output voltage 3-state	0	3.6	, v	
		V <sub>CC</sub> = 1.65 V to 1.95 V	-4		
lohs	Static high-level output current <sup>†</sup>	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-8	mA
		V <sub>CC</sub> = 3 V to 3.6 V		-12	
lous		V <sub>CC</sub> = 1.65 V to 1.95 V		4	
	Static low-level output current <sup>†</sup> V <sub>CC</sub> = 2.3 V to 2.7 V			8	mA
		V <sub>CC</sub> = 3 V to 3.6 V		12	
Δt/Δv	Input transition rise or fall rate	V <sub>CC</sub> = 1.65 V to 3.6 V		5	ns/V
TA	Operating free-air temperature	<u>-</u>	-40	85	°C

<sup>†</sup> Dynamic drive capability is equivalent to standard outputs with I<sub>OH</sub> and I<sub>OL</sub> of ±24 mA at 2.5-V V<sub>CC</sub>. See Figure 1 for V<sub>OL</sub> vs I<sub>OL</sub> and V<sub>OH</sub> vs I<sub>OH</sub> characteristics. Refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number **SCEA006**, and *Dynamic Output Control (DOC™) Circuitry Technology and Applications*, literature number **SCEA009**.

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



# PRODUCT PREVIEW

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT		
V		I <sub>OHS</sub> = -100 μA	I <sub>OHS</sub> = -100 μA		Vcc-0	.2				
		$I_{OHS} = -4 \text{ mA},$	V <sub>IH</sub> = 1.07 V	1.65 V	1.2			v		
VOH		$I_{OHS} = -8 \text{ mA},$	V <sub>IH</sub> = 1.7 V	2.3 V	1.75			٠		
		$I_{OHS} = -12 \text{ mA},$	V <sub>IH</sub> = 2 V	3 V	2.3					
		I <sub>OLS</sub> = 100 μA		1.65 V to 3.6 V			0.2	1		
V		I <sub>OLS</sub> = 4 mA,	V <sub>IL</sub> = 0.57 V	1.65 V			0.45			
VOL		I <sub>OLS</sub> = 8 mA,	$V_{IL} = 0.7 V$	2.3 V			0.55	V		
		$I_{OLS} = 12 \text{ mA},$	$V_{IL} = 0.8 V$	3 V			0.7			
Ц	Control inputs	V <sub>I</sub> = V <sub>CC</sub> or GND		3.6 V			±2.5	μΑ		
l <sub>off</sub>		V <sub>I</sub> = 0 or 3.6 V		0			±10	μΑ		
loz		V <sub>O</sub> = V <sub>CC</sub> or GND		3.6 V			±12.5	μΑ		
Icc		V <sub>I</sub> = V <sub>CC</sub> or GND,	I <sub>O</sub> = 0	3.6 V			40	μΑ		
	Controllinguite			2.5 V						
•	Control inputs	V V CND		3.3 V						
Ci	Data inputs	Al = ACC or GMD	I = V <sub>CC</sub> or GND					pF		
_	Out-ut-	V- V CND	V CND							
Со	Outputs	Outputs $V_O = V_{CC}$ or GND		AO = ACC  of GMD		3.3 V				pF

<sup>†</sup> Typical values are measured at T<sub>A</sub> = 25°C.

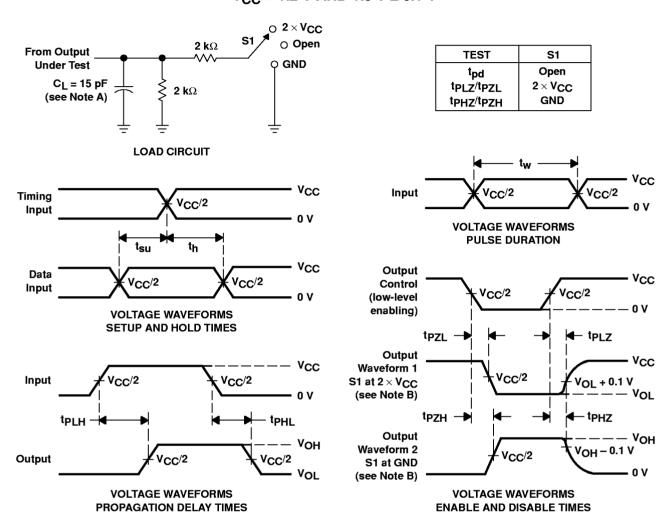
# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 2 through 5)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> =	1.5 V 1 V	V <sub>CC</sub> = ± 0.1		V <sub>CC</sub> =		V <sub>CC</sub> = ± 0.3		UNIT
	(INFOT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
<sup>t</sup> pd	Α	Υ										ns
t <sub>en</sub>	ŌĒ	Υ										ns
<sup>t</sup> dis	ŌĒ	Y										ns

# operating characteristics, $T_A = 25^{\circ}C$

PARAMETER		DADAMETED	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	CC = 1.8 V V <sub>CC</sub> = 2.5 V		UNIT
		FARAMETER	TEST CONDITIONS	TYP	TYP TYP		UNIT
ſ	C <sub>pd</sub>	Power dissipation capacitance per buffer	$C_L = 0$ , $f = 10 \text{ MHz}$				pF

## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.2 \text{ V AND } 1.5 \text{ V} \pm 0.1 \text{ V}$



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{O}$  = 50  $\Omega$ ,  $t_{f} \leq$  2 ns,  $t_{f} \leq$  2 ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F. tpzL and tpzH are the same as ten.
  - G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



VCC

0 V

VCC

0 V

· VCC

- Vol

– V<sub>ОН</sub>

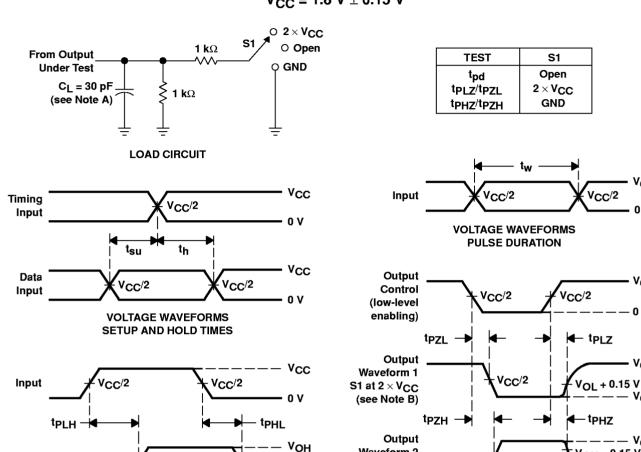
0 V

OH - 0.15 V

**VOLTAGE WAVEFORMS** 

**ENABLE AND DISABLE TIMES** 

## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

Output

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \ \Omega$ ,  $t_f \leq 2 \ ns$ ,  $t_f \leq 2 \ ns$ .

Waveform 2

(see Note B)

S1 at GND

D. The outputs are measured one at a time with one transition per measurement.

VCC/2

VOL

E. tpLZ and tpHZ are the same as tdis.

V<sub>CC</sub>/2

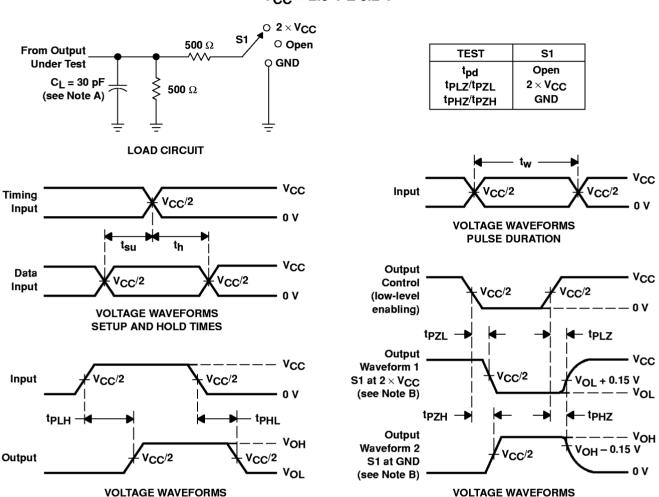
**VOLTAGE WAVEFORMS** 

**PROPAGATION DELAY TIMES** 

- F. tpzL and tpzH are the same as ten.
- G. tplH and tpHL are the same as tod.

Figure 3. Load Circuit and Voltage Waveforms

# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



- NOTES: A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \ \Omega$ ,  $t_f \leq$  2 ns.  $t_f \leq$  2 ns.

**ENABLE AND DISABLE TIMES** 

- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.

**PROPAGATION DELAY TIMES** 

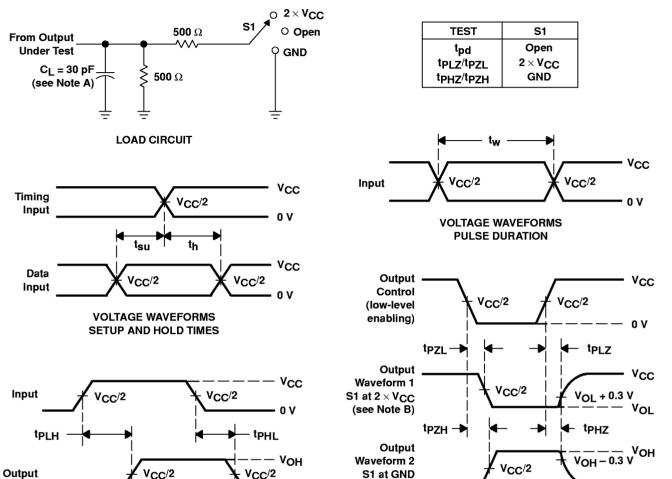
- F. tpzL and tpzH are the same as ten.
- G. tplH and tpHL are the same as tpd.

Figure 4. Load Circuit and Voltage Waveforms



0 V

# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

VOL

C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq$  2 ns,  $t_f \leq$  2 ns.

(see Note B)

**VOLTAGE WAVEFORMS** 

**ENABLE AND DISABLE TIMES** 

- D. The outputs are measured one at a time with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .

**VOLTAGE WAVEFORMS** 

**PROPAGATION DELAY TIMES** 

- F.  $tp_{ZL}$  and  $tp_{ZH}$  are the same as  $t_{en}$ .
- G. tpLH and tpHL are the same as tpd.

Figure 5. Load Circuit and Voltage Waveforms

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